Small Signal MOSFET

60 V, 115 mA, N-Channel SOT-23

Features

- 2V Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable (2V7002L)
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	60	Vdc
Drain–Gate Voltage (R_{GS} = 1.0 MΩ)	V _{DGR}	60	Vdc
Drain Current - Continuous $T_C = 25^{\circ}C$ (Note 1) $T_C = 100^{\circ}C$ (Note 1) - Pulsed (Note 2)	I _D I _D	±115 ±75 ±800	mAdc
Gate-Source Voltage - Continuous - Non-repetitive (t _p ≤ 50 μs)	V _{GS} V _{GSM}	±20 ±40	Vdc Vpk

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 3) T _A = 25°C Derate above 25°C Thermal Resistance, Junction-to-Ambient	P_D	225 1.8 556	mW mW/°C °C/W
Total Device Dissipation (Note 4) Alumina Substrate, T _A = 25°C Derate above 25°C Thermal Resistance, Junction–to–Ambient	P _D	300 2.4 417	mW mW/°C °C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

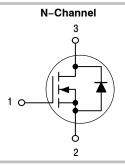
- The Power Dissipation of the package may result in a lower continuous drain current.
- 2. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.
- 3. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.
- 4. Alumina = 0.4 x 0.3 x 0.025 in 99.5% alumina.

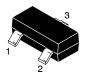


ON Semiconductor®

http://onsemi.com

V _{(BR)DSS}	R _{DS(on)} MAX	I _D MAX
60 V	7.5 Ω @ 10 V, 500 mA	115 mA





DIAGRAM

MARKING

702 M=

SOT-23 CASE 318 STYLE 21

> 702 = Device Code M = Date Code* ■ Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation and/or position may
vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]		
2N7002LT1G	SOT-23	3000 Tape & Reel		
2N7002LT3G	(Pb-Free)	10,000 Tape & Reel		
2V7002LT1G		3000 Tape & Reel		
2V7002LT3G	SOT-23	10,000 Tape & Reel		
2N7002LT1H*	(Pb-Free)	3000 Tape & Reel		

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}Not for new design.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage ($V_{GS} = 0$, $I_D = 10 \mu Adc$)	V _{(BR)DSS}	60	-	-	Vdc	
Zero Gate Voltage Drain Current $T_J = 25^{\circ}C$ $(V_{GS} = 0, V_{DS} = 60 \text{ Vdc})$ $T_J = 125^{\circ}C$		-		1.0 500	μAdc	
Gate-Body Leakage Current, Forward (V _{GS} = 20 Vdc)	I _{GSSF}	_	-	100	nAdc	
Gate-Body Leakage Current, Reverse (V _{GS} = -20 Vdc)	I _{GSSR}	-	-	-100	nAdc	
ON CHARACTERISTICS (Note 5)						
Gate Threshold Voltage (V _{DS} = V _{GS} , I _D = 250 μAdc)	V _{GS(th)}	1.0	-	2.5	Vdc	
On–State Drain Current $(V_{DS} \ge 2.0 V_{DS(on)}, V_{GS} = 10 \text{ Vdc})$	I _{D(on)}	500	-	_	mA	
Static Drain–Source On–State Voltage $(V_{GS} = 10 \text{ Vdc}, I_D = 500 \text{ mAdc})$ $(V_{GS} = 5.0 \text{ Vdc}, I_D = 50 \text{ mAdc})$	V _{DS(on)}	- -	- -	3.75 0.375	Vdc	
$ \begin{array}{llllllllllllllllllllllllllllllllllll$;	- - -	- - - -	7.5 13.5 7.5 13.5	Ohms	
Forward Transconductance ($V_{DS} \ge 2.0 V_{DS(on)}$, $I_D = 200 \text{ mAdc}$)	9 _{FS}	80	-	_	mS	
DYNAMIC CHARACTERISTICS	Į.		I		1	
Input Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)	C _{iss}	-	_	50	pF	
Output Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)	C _{oss}	-	-	25	pF	
Reverse Transfer Capacitance (V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)	C _{rss}	-	-	5.0	pF	
SWITCHING CHARACTERISTICS (Note 5)	<u>'</u>		1	•	•	
Turn–On Delay Time $(V_{DD} = 25 \text{ Vdc}, I_D \approx 500 \text{ mAdc},$	t _{d(on)}	-	-	20	ns	
Turn–Off Delay Time $R_G = 25 \Omega$, $R_L = 50 \Omega$, $V_{gen} = 10 V$)	t _{d(off)}	-	-	40	ns	
BODY-DRAIN DIODE RATINGS						
Diode Forward On-Voltage (I _S = 11.5 mAdc, V _{GS} = 0 V)	V _{SD}	_	-	-1.5	Vdc	
Source Current Continuous (Body Diode)	I _S	_	-	-115	mAdc	
Source Current Pulsed	I _{SM}	-	-	-800	mAdc	
	•					

^{5.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

TYPICAL ELECTRICAL CHARACTERISTICS

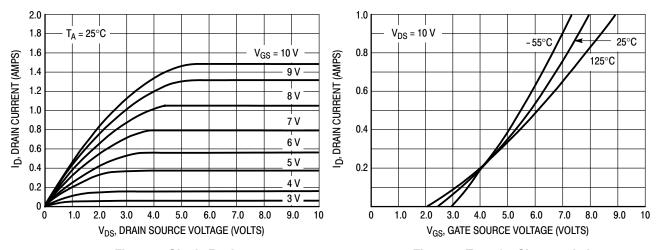


Figure 1. Ohmic Region

Figure 2. Transfer Characteristics

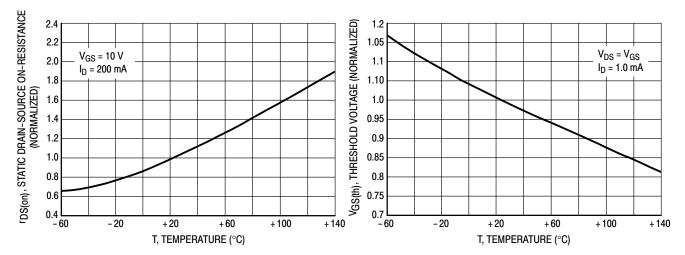
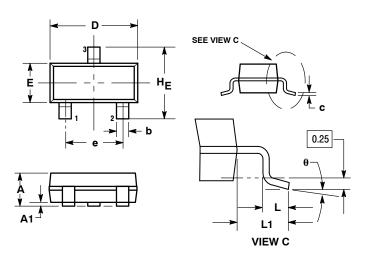


Figure 3. Temperature versus Static Drain-Source On-Resistance

Figure 4. Temperature versus Gate Threshold Voltage

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AP**



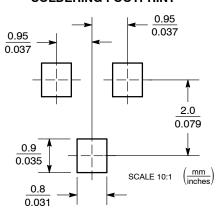
NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104
θ	0°		10°	0°		10°

STYLE 21:

- PIN 1. GATE SOURCE
 - 2. 3. DRAIN
- **SOLDERING FOOTPRINT**



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